HALOGEN

FREE



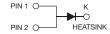
Vishay General Semiconductor

High Current Density Surface-Mount TMBS® (Trench MOS Barrier Schottky) Rectifier

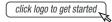
Ultra Low $V_F = 0.49 \text{ V}$ at $I_F = 5 \text{ A}$



SlimDPAK (TO-252AE)



DESIGN SUPPORT TOOLS





| PRIMARY CHARACTERISTICS | | | |
|---|---------------------|--|--|
| I _{F(AV)} | 20 A | | |
| V _{RRM} | 120 V | | |
| I _{FSM} | 200 A | | |
| V _F at I _F = 20 A (T _A = 125 °C) | 0.72 V | | |
| T _J max. | 150 °C | | |
| Package | SlimDPAK (TO-252AE) | | |
| Circuit configuration | Single | | |

FEATURES

- Very low profile typical height of 1.3 mm
- Trench MOS Schottky technology
- Ideal for automated placement
- · Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
 - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in low voltage high frequency DC/DC converters, freewheeling diodes, and polarity protection applications.

MECHANICAL DATA

Case: SlimDPAK (TO-252AE)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test

| MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted) | | | | |
|--|-------------------------------|-------------|------|--|
| PARAMETER | SYMBOL | V20PW12 | UNIT | |
| Device marking code | | V20PW12 | | |
| Maximum repetitive peak reverse voltage | V _{RRM} | 120 | V | |
| Maximum average forward rectified current (Fig. 1) | I _{F(AV)} (1) | 20 | А | |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load | I _{FSM} | 200 | А | |
| Operating junction temperature range | T _J ⁽²⁾ | -40 to +150 | °C | |
| Storage temperature range | T _{STG} | -55 to +150 | °C | |

Notes

- (1) With infinite heatsink
- $^{(2)}$ The heat generated must be less than the thermal conductivity from junction to ambient: $dP_D/dT_J < 1/R_{\theta JA}$



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| ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | | |
|---|------------------------|-------------------------|---------------------------------|------|------|------|
| PARAMETER | TEST CONDITIONS | | SYMBOL | TYP. | MAX. | UNIT |
| Maximum Instantaneous forward voltage | $I_F = 5.0 \text{ A}$ | T _A = 25 °C | - V _F ⁽¹⁾ | 0.54 | - | V |
| | I _F = 10 A | | | 0.68 | - | |
| | I _F = 20 A | | | 0.94 | 1.02 | |
| | I _F = 5.0 A | T _A = 125 °C | | 0.49 | - | |
| | I _F = 10 A | | | 0.60 | - | |
| | I _F = 20 A | | | 0.72 | 0.80 | |
| Reverse current | V _R = 90 V | T _A = 25 °C | I _R ⁽²⁾ | 0.05 | - | mA |
| | V _R = 90 V | T _A = 125 °C | | 8 | - | |
| | V _R = 120 V | T _A = 25 °C | | - | 0.8 | |
| | | T _A = 125 °C | | 16 | 40 | |
| Typical junction capacitance | 4.0 V, 1 MHz | | CJ | 1350 | - | pF |

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: pulse width ≤ 5 ms

| THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | |
|---|-------------------------|-----|-------|--|
| PARAMETER | SYMBOL V20PW12 | | | |
| Tuning thermal registeres | R _{θJA} (1)(2) | 55 | °C/W | |
| Typical thermal resistance | R _{0JM} (3) | 2.0 |] C/W | |

Notes

- $^{(1)}$ The heat generated must be less than thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$
- $^{(2)}$ Free air, mounted on recommended copper pad area; thermal resistance $R_{\theta JA}$ junction to ambient
- $^{(3)}$ Mounted on infinite heat sink; thermal resistance $R_{\theta JM}$ junction-to-mount

| ORDERING INFORMATION (Example) | | | | | |
|--|------|---------------|---------------|------------------------------------|--|
| PREFERRED P/N UNIT WEIGHT (g) PREFERRED PACKAGE CODE | | BASE QUANTITY | DELIVERY MODE | | |
| V20PW12-M3/I | 0.20 | 1 | 4500 | 13" diameter plastic tape and reel | |
| V20PW12HM3/I (1) | 0.20 | I | 4500 | 13" diameter plastic tape and reel | |

Note

(1) AEC-Q101 qualified

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

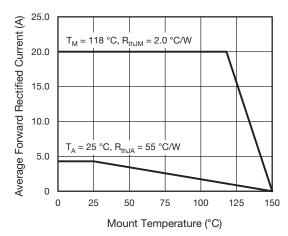


Fig. 1 - Maximum Forward Current Derating Curve

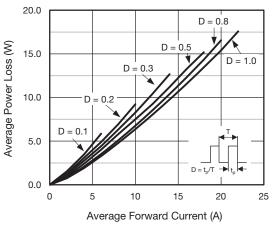


Fig. 2 - Forward Power Loss Characteristics

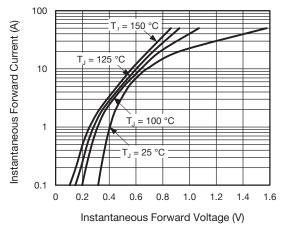


Fig. 3 - Typical Instantaneous Forward Characteristics

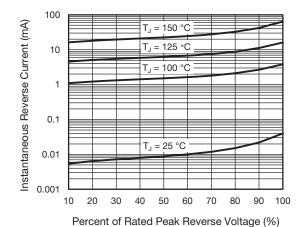


Fig. 4 - Typical Reverse Leakage Characteristics

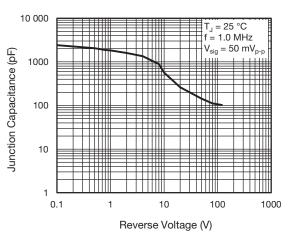


Fig. 5 - Typical Junction Capacitance

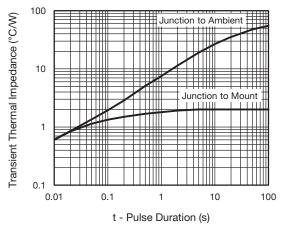


Fig. 6 - Typical Transient Thermal Impedance



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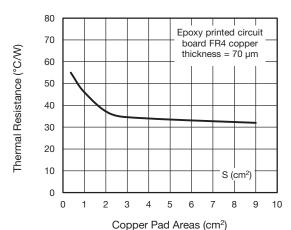
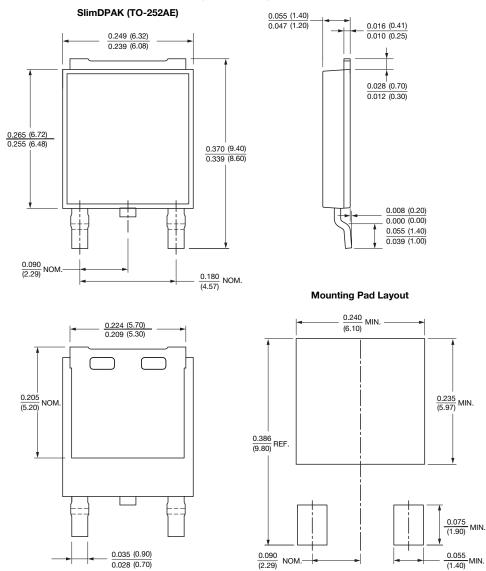


Fig. 7 - Typical Resistance Junction to Ambient vs. Copper Pad Areas

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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